

200 V, 3 A Silicon Germanium (SiGe) rectifier

22 June 2020

Product data sheet

1. General description

Silicon Germanium (SiGe) rectifier encapsulated in a CFP5 (SOD128) small and flat lead Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

| Features | Benefits | | | | |
|--|---|--|--|--|--|
| Low forward voltage and low Q_{rr} Extremely low leakage current Thermal stability up to 175 °C junction temperature Fast and smooth switching Low parasitic capacitance AEC-Q101 gualified | Excellent efficiency Extraordinary safe operating area Minimal impact on Electro-Magnetic Compatibility (EMC) allowing simplified certification | | | | |

3. Applications

- High-efficiency power conversion
 - Automotive LED lighting
 - Engine control unit
 - Server power supply
 - Base station power supply
- Reverse polarity protection
- OR-ing

4. Quick reference data

| Table 1. Qui | ck reference data | | | | | | |
|--------------------|-------------------------|--|-----|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| I _{F(AV)} | average forward current | δ = 0.5; square wave; f = 20 kHz; T _{sp} ≤ 160 °C | | - | - | 3 | A |
| V _R | reverse voltage | T _j = 25 °C | | - | - | 200 | V |
| V _F | forward voltage | I _F = 3 A; T _j = 25 °C; pulsed | [1] | - | 810 | 880 | mV |
| I _R | reverse current | V _R = 200 V; T _j = 25 °C; pulsed | [1] | - | 0.7 | 30 | nA |
| | | V _R = 200 V; T _j = 150 °C; pulsed | [1] | - | 40 | 400 | μA |

[1] Very short pulse, in order to maintain a stable junction temperature.

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5. Pinning information

| Table 2 | . Pinning info | rmation | | |
|---------|----------------|-------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | К | cathode | | |
| 2 | A | anode | | 006aab040 |
| | | | CFP5 (SOD128) | |

6. Ordering information

| Table 3. Ordering information | | | | | | |
|-------------------------------|------|--|---------|--|--|--|
| Type number Package | | | | | | |
| | Name | Description | Version | | | |
| PMEG200G30ELP | | plastic, surface mounted package; 2 terminals; 4 mm pitch; 3.8 mm x 2.6 mm x 1 mm body | SOD128 | | | |

7. Marking

| Table 4. Marking codes | |
|------------------------|--------------|
| Type number | Marking code |
| PMEG200G30ELP | ED |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Attention: Stress above one of these maximum values may cause irreversible damage to the device.

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|--------------------|--|--|-----|-----|------|------|
| V _R | reverse voltage | T _j = 25 °C | | - | 200 | V |
| I _F | forward current | δ = 1; T _{sp} ≤ 155 °C | | - | 4.2 | А |
| I _{F(AV)} | average forward current | δ = 0.5; square wave; f = 20 kHz; T _{sp} ≤ 160 °C | | - | 3 | A |
| I _{FSM} | non-repetitive peak forward current | t_p = 8.3 ms; half sine wave; $T_{j(init)}$ = 25 °C | | - | 85 | A |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 0.75 | W |
| | | | [2] | - | 1.2 | W |
| Tj | junction temperature | | | - | 175 | °C |
| T _{amb} | ambient temperature | | | -55 | 175 | °C |
| T _{stg} | storage temperature | | | -65 | 175 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

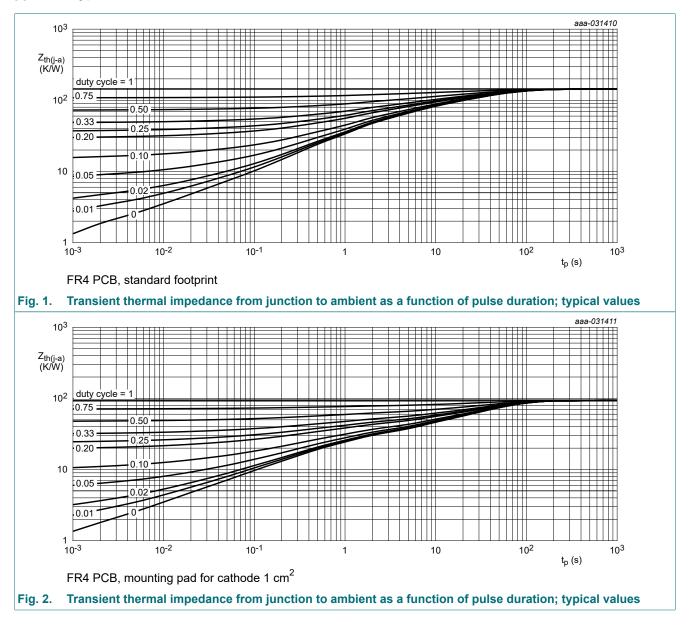
9. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| ulu-a) | thermal resistance from | in free air | [1] | - | - | 200 | K/W |
| | junction to ambient | | [2] | - | - | 120 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | [3] | - | - | 12 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[3] Soldering point of cathode tab.

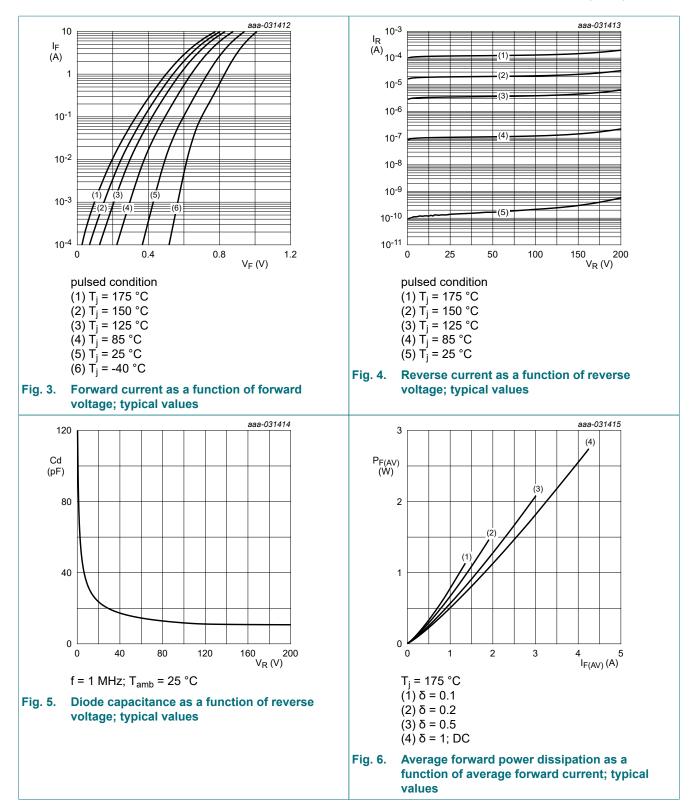


10. Characteristics

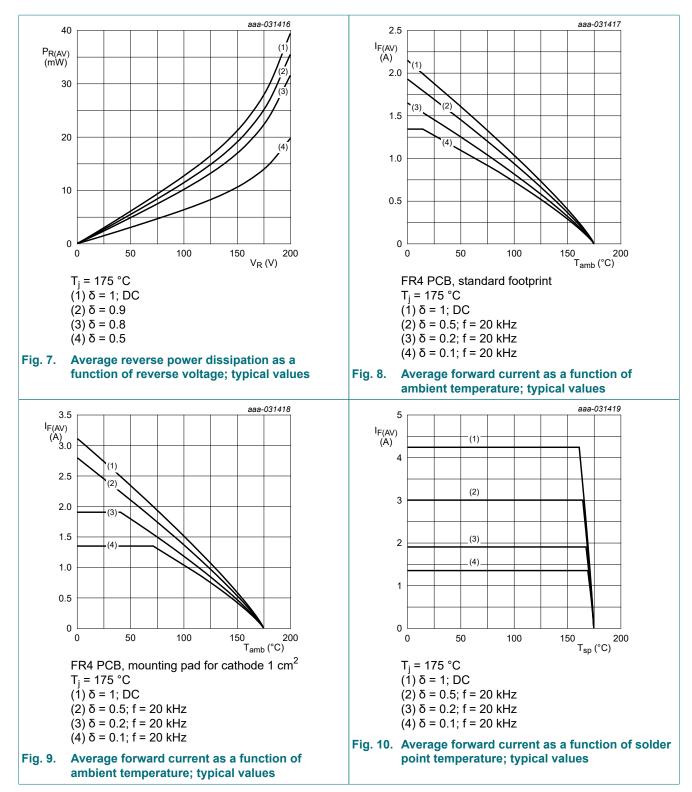
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------------|--|--|-----|-----|-----|-----|------|
| V _{(BR)R} | reverse breakdown voltage | I_R = 1 mA; pulsed; T_j = 25 °C | [1] | 200 | - | - | V |
| V _F | forward voltage | I _F = 0.1 A; T _j = 25 °C; pulsed | [1] | - | 600 | 690 | mV |
| | | I _F = 0.5 A; T _j = 25 °C; pulsed | [1] | - | 690 | 770 | mV |
| | | I _F = 1 A; T _j = 25 °C; pulsed | [1] | - | 735 | 810 | mV |
| | | I _F = 2 A; T _j = 25 °C; pulsed | [1] | - | 780 | 850 | mV |
| | | I _F = 3 A; T _j = 25 °C; pulsed | [1] | - | 810 | 880 | mV |
| | | I _F = 3 A; T _j = -40 °C; pulsed | [1] | - | 900 | 990 | mV |
| | | I _F = 3 A; T _j = 125 °C; pulsed | [1] | - | 670 | 770 | mV |
| I _R | reverse current | V_R = 200 V; T_j = 25 °C; pulsed | [1] | - | 0.7 | 30 | nA |
| | | V _R = 200 V; T _j = 125 °C; pulsed | [1] | - | 7 | 70 | μA |
| | | V _R = 200 V; T _j = 150 °C; pulsed | [1] | - | 40 | 400 | μA |
| C _d diode c | diode capacitance | V _R = 1 V; f = 1 MHz; T _j = 25 °C | | - | 80 | - | pF |
| | | V _R = 10 V; f = 1 MHz; T _j = 25 °C | | - | 31 | - | pF |
| t _{rr} | reverse recovery time step recovery | $I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(meas)} = 0.25 \text{ A};$ $T_j = 25 ^{\circ}\text{C}$ | | - | 14 | - | ns |
| | reverse recovery time ramp recovery | dI _F /dt = 100 A/µs; I _F = 1 A; V _R = 30 V; T _j = 25 °C | | - | 31 | - | ns |
| I _{RM} | peak reverse recovery current | | | - | 1 | - | A |
| Q _{rr} | reverse recovery charge | | | - | 17 | - | nC |
| V _{FRM} | peak forward recovery voltage | $I_F = 0.5 \text{ A}; \text{ d}_F/\text{d}t = 20 \text{ A}/\mu\text{s}; T_j = 25 \text{ °C}$ | | - | 765 | - | mV |

[1] Very short pulse, in order to maintain a stable junction temperature.

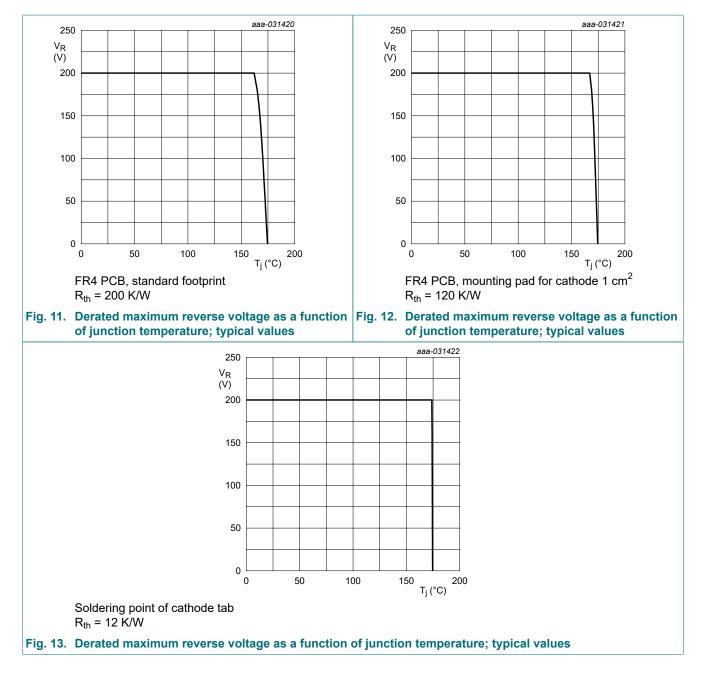
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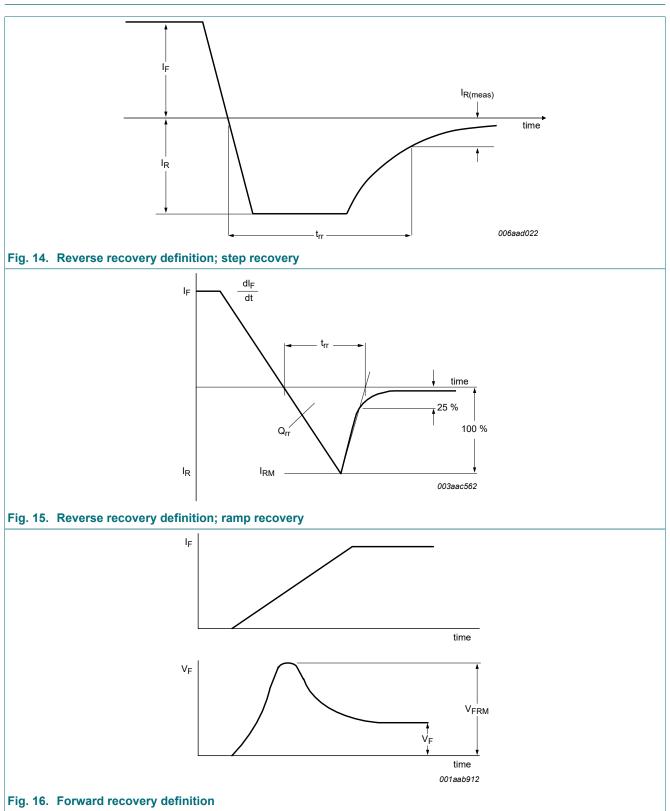
200 V, 3 A Silicon Germanium (SiGe) rectifier



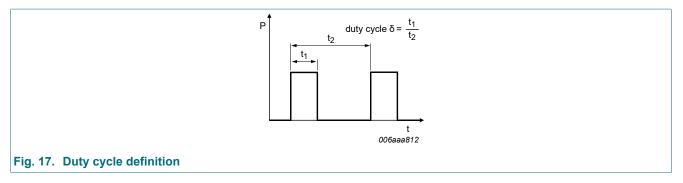
200 V, 3 A Silicon Germanium (SiGe) rectifier



11. Test information



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The current ratings for the typical waveforms are calculated according to the equations:

 $I_{F(AV)}=I_M \times \delta$ with I_M defined as peak current

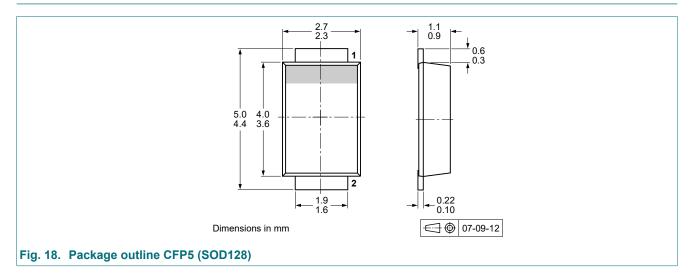
 $I_{RMS}=I_{F(AV)}$ at DC, and $I_{RMS}=I_M \times \sqrt{\delta}$

with $\mathsf{I}_{\mathsf{RMS}}$ defined as RMS current.

Quality information

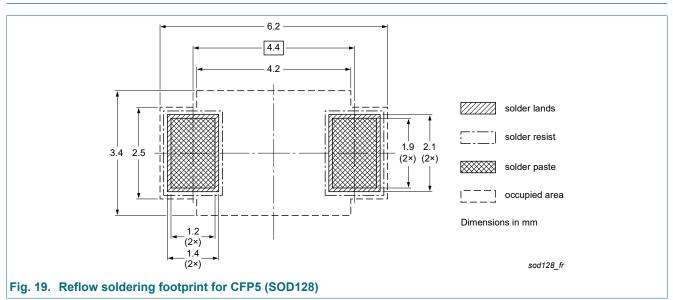
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline

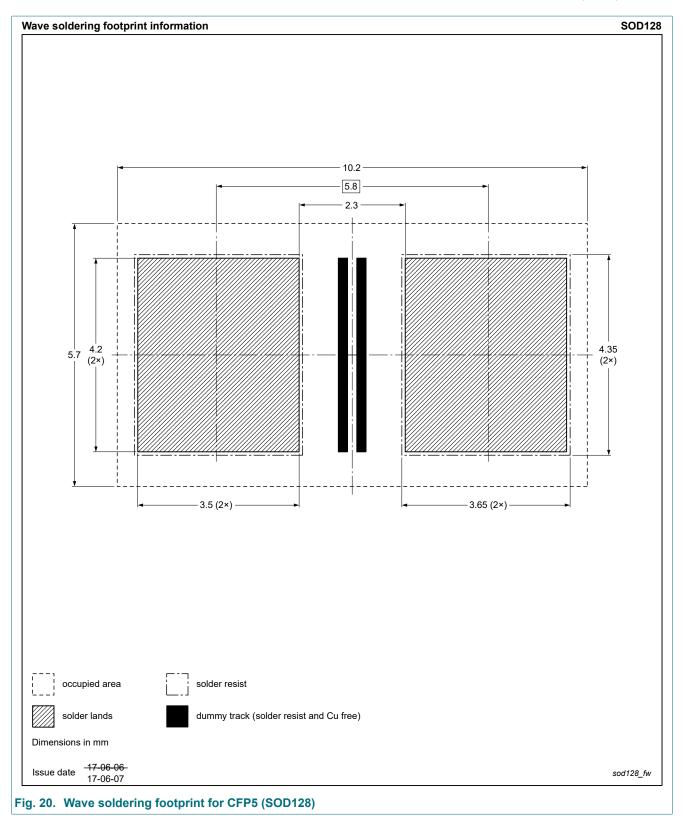


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13. Soldering



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14. Mounting

This device is sensitive to Electro Static Discharge (ESD). Observe precautions for handling electrostatic sensitive devices. Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

15. Revision history

| Table 8. Revision history | | | | |
|---------------------------|--------------|--------------------|---------------|------------|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
| PMEG200G30ELP v.1 | 20200622 | Product data sheet | - | - |

16. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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